

# OPA337, OPA2337 OPA338, OPA2338

SBOS077B - JUNE 1997 - REVISED MARCH 2005

# MicroSIZE, Single-Supply CMOS OPERATIONAL AMPLIFIERS MicroAmplifier™ Series

#### **FEATURES**

- MicroSIZE PACKAGES: SOT23-5, SOT23-8
- SINGLE-SUPPLY OPERATION
- RAIL-TO-RAIL OUTPUT SWING
- FET-INPUT: I<sub>B</sub> = 10pA max
- HIGH SPEED:

OPA337: 3MHz, 1.2V/ $\mu$ s (G = 1) OPA338: 12.5MHz, 4.6V/ $\mu$ s (G = 5)

- OPERATION FROM 2.5V to 5.5V
- HIGH OPEN-LOOP GAIN: 120dB
- LOW QUIESCENT CURRENT: 525µA/amp
- SINGLE AND DUAL VERSIONS

#### **APPLICATIONS**

- BATTERY-POWERED INSTRUMENTS
- PHOTODIODE PRE-AMPS
- MEDICAL INSTRUMENTS
- TEST EQUIPMENT
- AUDIO SYSTEMS
- DRIVING ADCs
- CONSUMER PRODUCTS

SPICE model available at www.ti.com.

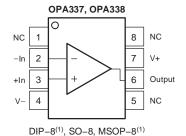
#### DESCRIPTION

The OPA337 and OPA338 series rail-to-rail output CMOS operational amplifiers are designed for low cost and miniature applications. Packaged in the SOT23-8, the OPA2337EA and OPA2338EA are Texas Instruments' smallest dual op amps. At 1/4 the size of a conventional SO-8 surface-mount, they are ideal for space-sensitive applications.

Utilizing advanced CMOS technology, the OPA337 and OPA338 op amps provide low bias current, high-speed operation, high open-loop gain, and rail-to-rail output swing. They operate on a single supply with operation as low as 2.5V while drawing only 525µA quiescent current. In addition, the input common-mode voltage range includes ground—ideal for single-supply operation.

The OPA337 series is unity-gain stable. The OPA338 series is optimized for gains greater than or equal to 5. They are easy-to-use and free from phase inversion and overload problems found in some other op amps. Excellent performance is maintained as the amplifiers swing to their specified limits. The dual versions feature completely independent circuitry for lowest crosstalk and freedom from interaction, even when overdriven or overloaded.

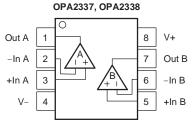
	G = 1 S	TABLE	G ≥ 5 S	TABLE
PACKAGE	SINGLE OPA337	DUAL OPA2337	SINGLE OPA338	DUAL OPA2338
SOT23-5	~		~	
SOT23-8		~		~
MSOP-8	<b>V</b>			
SO-8	<b>/</b>	~	V	~
DIP-8	V	~		



NC = No Connection

Out 1 5 V+ V- 2 + - 4 - In SOT23-5

OPA337, OPA338



NOTE: (1) DIP AND MSOP-8 versions for OPA337, OPA2337 only.

DIP-8<sup>(1)</sup>, SO-8, SOT23-8



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#### **ABSOLUTE MAXIMUM RATINGS(1)**

Supply Voltage 7.5V
Input Voltage(2) $(V-) - 0.5V$ to $(V+) + 0.5V$
Input Current <sup>(2)</sup>
Output Short Circuit <sup>(3)</sup> Continuous
Operating Temperature55°C to +125°C
Storage Temperature55°C to +125°C
Junction Temperature
Lead Temperature (soldering, 10s)

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not supported.
- (2) Input signal voltage is limited by internal diodes connected to power supplies. See text.
- (3) Short-circuit to ground, one amplifier per package.

# 180

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe

proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### ORDERING INFORMATION(1)

PRODUCT	DESCRIPTION	PACKAGE-LEAD	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY	
OPA337 Series								
		0.0700.5	DBV		007	OPA337NA/250	Tape and Reel, 250	
		SOT23-5	DBA		C37	OPA337NA/3K	Tape and Reel, 3000	
		Single MSOP-8 DGK		G37	OPA337EA/250	Tape and Reel, 250		
OPA337	Single, G = 1 Stable	MSOP-8	MSOP-8 DGK -40°C to +85°C		G37	OPA337EA/2K5	Tape and Reel, 2500	
	0 = 1 Glabic	DIP-8	Р		OPA337PA	OPA337PA	Rails	
		SO-8	D		OPA337UA	OPA337UA	Rails	
		Surface-Mount	D		OPA337UA	OPA337UA/2K5	Tape and Reel, 2500	
		SOT23-8			A7	OPA2337EA/250	Tape and Reel, 250	
				Α/	OPA2337EA/3K	Tape and Reel, 3000		
OPA2337	Dual, G = 1 Stable	'' I I)IP-8 I P I 40°C to ±95°C		OPA2337PA	OPA2337PA	Rails		
	G = 1 Glabic	G = 1 Glabic	G = 1 Glable	G = 1 Glable	SO-8	OPA2337UA	OPA2337UA	Rails
		Surface-Mount	Б		OFA23370A	OPA2337UA/2K5	Tape and Reel, 2500	
OPA338 Series								
		SOT23-5	DBV		A38	OPA338NA/250	Tape and Reel, 250	
OPA338	Single,	30123-3	DBV	-40°C to +85°C	ASO	OPA338NA/3K	Tape and Reel, 3000	
OFA336	G ≥ 5 Stable	SO-8	D	-40 C to +65 C	OPA338UA	OPA338UA	Rails	
		Surface-Mount	D		OFA3360A	OPA338UA/2K5	Tape and Reel, 2500	
		SOT23-8	DCN		A8	OPA2338EA/250	Tape and Reel, 250	
OPA2338	Dual,	30123-0	DCN	-40°C to +85°C	Ao	OPA2338EA/3K	Tape and Reel, 3000	
OFA2330	G ≥ 5 Stable	SO-8	D	-40 C to +65°C	OPA2338UA	OPA2338UA	Rails	
		Surface-Mount	D		OFA2330UA	OPA2338UA/2K5	Tape and Reel, 2500	

<sup>(1)</sup> For the most current package and ordering information, see the Package Option Addendum located at the end of this data sheet.



ELECTRICAL CHARACTERISTICS:  $V_S = 2.7V$  to 5.5V Boldface limits apply over the specified temperature range, -40°C to +85°C,  $V_S = 5V$ .

At  $T_A = +25^{\circ}C$  and  $R_L = 25k\Omega$  connected to  $V_S/2$ , unless otherwise noted.

				A337, OPA2 A338, OPA2		
PARAMETER		CONDITION	MIN	TYP(1)	MAX	UNIT
OFFSET VOLTAGE						
Input Offset Voltage	Vos			±0.5	±3	mV
$T_A = -40^{\circ}C$ to $+85^{\circ}C$					±3.5	mV
vs Temperature	dV <sub>OS</sub> /dT			±2		μV/°C
vs Power-Supply Rejection Ratio	PSRR	$V_S = 2.7V \text{ to } 5.5V$		25	125	μV/V
$T_A = -40^{\circ}C$ to $+85^{\circ}C$		$V_S = 2.7V \text{ to } 5.5V$			125	μV/V
Channel Separation (dual versions)		dc		0.3		μV/V
INPUT BIAS CURRENT						
Input Bias Current	$I_{B}$			±0.2	±10	pА
$T_A = -40^{\circ}C$ to $+85^{\circ}C$			Se	ee Typical Cu	rve	
Input Offset Current	los			±0.2	±10	pА
NOISE						
Input Voltage Noise, f = 0.1Hz to 10Hz				6		μVpp
Input Voltage Noise Density, f = 1kHz	en			26		nV/√ <del>Hz</del>
Current Noise Density, f = 1kHz	i <sub>n</sub>			0.6		fA/√Hz
INPUT VOLTAGE RANGE	- 11					
Common-Mode Voltage Range	VCM	$T_{\Delta} = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$	-0.2		(V+) - 1.2	V
Common-Mode Rejection Ratio	CMRR	$-0.2V < V_{CM} < (V+) - 1.2V$	74	90	(* ')	dB
T <sub>A</sub> = -40°C to +85°C	• • • • • • • • • • • • • • • • • • • •	-0.2V < V <sub>CM</sub> < (V+) - 1.2V	74			dB
INPUT IMPEDANCE		<b>S</b> III ( )				
Differential				1013   2		Ω   pF
Common-Mode				1013   4		Ω   pF
OPEN-LOOP GAIN						-
Open-Loop Voltage Gain	AOI	$R_{I} = 25k\Omega$ , $125mV < V_{O} < (V+) - 125mV$	100	120		dB
$T_A = -40^{\circ}C$ to $+85^{\circ}C$	02	$R_L = 25k\Omega$ , $125mV < V_O < (V+) - 125mV$	100			dB
		$R_L = 5k\Omega$ , 500mV < $V_O$ < (V+) – 500mV	100	114		dB
$T_A = -40^{\circ}C$ to $+85^{\circ}C$		$R_L = 5k\Omega$ , 500mV < $V_O$ < $(V+) - 500mV$	100			dB
OPA337 FREQUENCY RESPONSE						
Gain-Bandwidth Product	GBW	V <sub>S</sub> = 5V, G = 1		3		MHz
Slew Rate	SR	V <sub>S</sub> = 5V, G = 1		1.2		V/µs
Settling TIme: 0.1%		V <sub>S</sub> = 5V, 2V Step, C <sub>L</sub> = 100pF, G = 1		2		μs
0.01%		V <sub>S</sub> = 5V, 2V Step, C <sub>L</sub> = 100pF, G = 1		2.5		μs
Overload Recovery Time		$V_{IN} \times G = V_S$		2		μs
Total Harmonic Distortion + Noise	THD+N	$V_S = 5V$ , $V_O = 3V_{PP}$ , $G = 1$ , $f = 1kHz$		0.001		%
OPA338 FREQUENCY RESPONSE						
Gain-Bandwidth Product	GBW	V <sub>S</sub> = 5V, G = 5		12.5		MHz
Slew Rate	SR	V <sub>S</sub> = 5V, G = 5		4.6		V/μs
Settling TIme: 0.1%		V <sub>S</sub> = 5V, 2V Step, C <sub>L</sub> = 100pF, G = 5		1.4		μs
0.01%		V <sub>S</sub> = 5V, 2V Step, C <sub>L</sub> = 100pF, G = 5		1.9		μs
Overload Recovery Time		$V_{IN} \times G = V_S$		0.5		μs
Total Harmonic Distortion + Noise	THD+N	$V_S = 5V$ , $V_O = 3V_{PP}$ , $G = 5$ , $f = 1kHz$		0.0035		%

<sup>(1)</sup>  $V_S = 5V$ .

<sup>(2)</sup> Output voltage swings are measured between the output and negative and positive power-supply rails.



ELECTRICAL CHARACTERISTICS:  $V_S = 2.7V$  to 5.5V (continued) Boldface limits apply over the specified temperature range, -40°C to +85°C,  $V_S = 5V$ .

At  $T_A$  = +25°C and  $R_L$  = 25k $\Omega$  connected to  $V_S/2$ , unless otherwise noted.

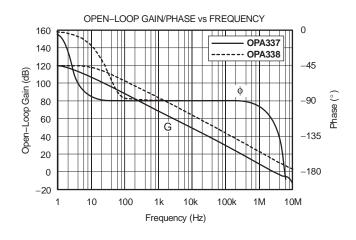
			OP OF			
PARAMETER		CONDITION	MIN	TYP(1)	MAX	UNIT
OUTPUT						
Voltage Output Swing from Rail <sup>(2)</sup>		$R_L = 25k\Omega$ , $A_{OL} \ge 100dB$		40	125	mV
$T_A = -40^{\circ}C$ to $+85^{\circ}C$		$R_L = 25k\Omega$ , $A_{OL} \ge 100dB$			125	mV
		$R_L = 5k\Omega$ , $A_{OL} \ge 100dB$		150	500	mV
$T_A = -40^{\circ}C$ to $+85^{\circ}C$		$R_L = 5k\Omega$ , $A_{OL} \ge 100dB$			500	mV
Short-Circuit Current				±9		mA
Capacitive Load Drive			Se	ee Typical Cu	rve	
POWER SUPPLY						
Specified Voltage Range	٧s	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	2.7		5.5	V
Minimum Operating Voltage				2.5		V
Quiescent Current (per amplifier)	IQ	IO = 0		0.525	1	mA
$T_A = -40^{\circ}C$ to $+85^{\circ}C$		IO = 0			1.2	mA
TEMPERATURE RANGE						
Specified Range			-40		+85	°C
Operating Range			-55		+125	°C
Storage Range			-55		+125	°C
Thermal Resistance	$\theta$ JA					
SOT23-5 Surface-Mount				200		°C/W
SOT23-8 Surface-Mount				200		°C/W
MSOP-8				150		°C/W
SO-8 Surface-Mount				150		°C/W
DIP-8				100		°C/W

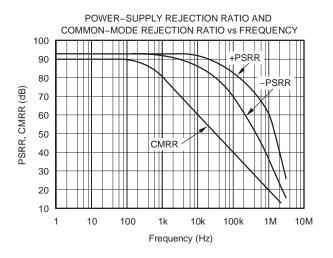
<sup>(2)</sup> Output voltage swings are measured between the output and negative and positive power-supply rails.

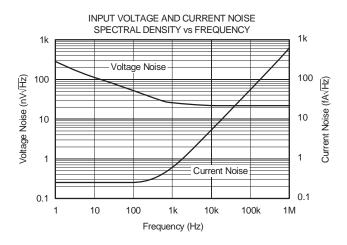


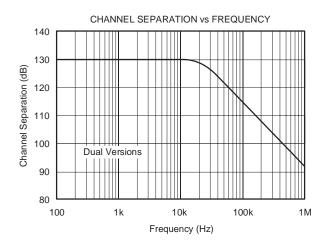
#### TYPICAL CHARACTERISTICS

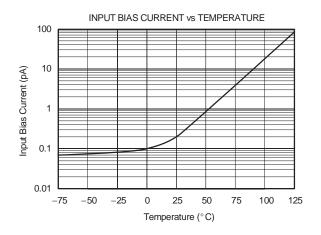
At  $T_A = +25^{\circ}C$ ,  $V_S = +5V$ , and  $R_L = 25k\Omega$  connected to  $V_S/2$ , unless otherwise noted.

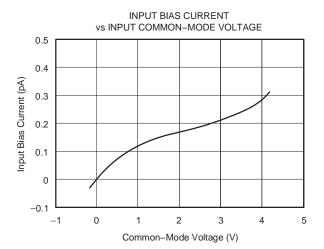








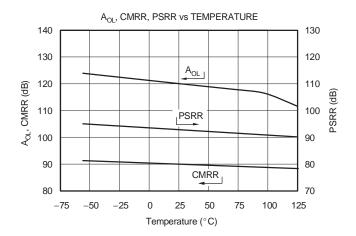


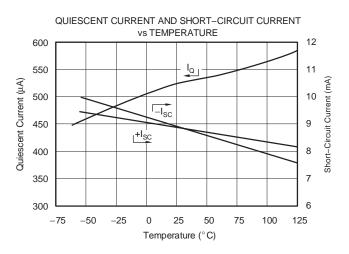


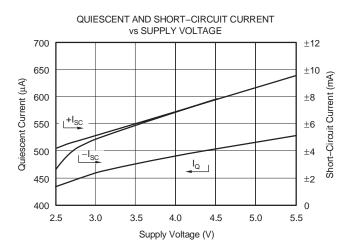


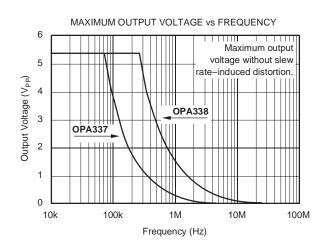
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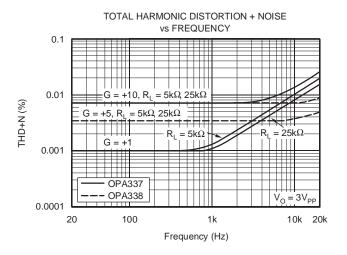
At  $T_A = +25$ °C,  $V_S = +5V$ , and  $R_L = 25k\Omega$  connected to  $V_S/2$ , unless otherwise noted.

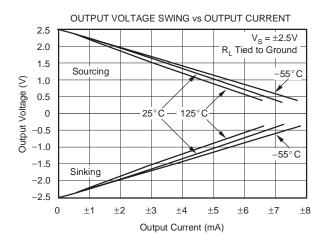








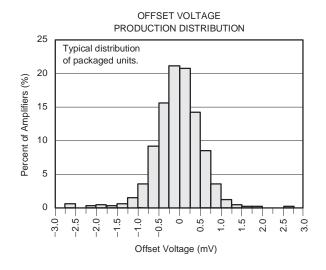


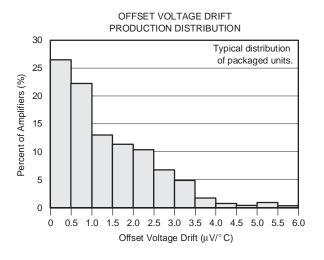


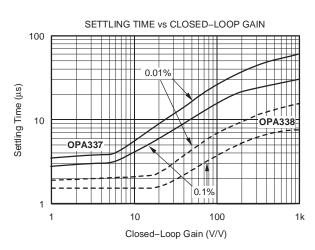


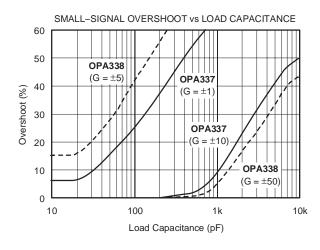
#### **TYPICAL CHARACTERISTICS (continued)**

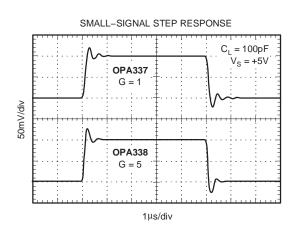
At  $T_A = +25$ °C,  $V_S = +5V$ , and  $R_L = 25k\Omega$  connected to  $V_S/2$ , unless otherwise noted.

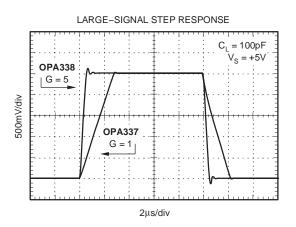














#### APPLICATIONS INFORMATION

The OPA337 and OPA338 series are fabricated on a state-of-the-art CMOS process. The OPA337 series is unity-gain stable. The OPA338 series is optimized for gains greater than or equal to 5. Both are suitable for a wide range of general-purpose applications. Power-supply pins should be bypassed with  $0.01\mu F$  ceramic capacitors.

#### **OPERATING VOLTAGE**

The OPA337 series and OPA338 series can operate from a +2.5V to +5.5V single supply with excellent performance. Unlike most op amps which are specified at only one supply voltage, these op amps are specified for real-world applications; a single limit applies throughout the +2.7V to +5.5V supply range. This allows a designer to have the same assured performance at any supply voltage within the specified voltage range. Most behavior remains unchanged throughout the full operating voltage range. Parameters which vary significantly with operating voltage are shown in the Typical Characteristic curves.

#### **INPUT VOLTAGE**

The input common-mode range extends from (V-) - 0.2V to (V+) - 1.2V. For normal operation, inputs should be limited to this range. The absolute maximum input voltage is 500mV beyond the supplies. Inputs greater than the input common-mode range but less than maximum input voltage, while not valid, will not cause any damage to the op amp. Furthermore, if input current is limited the inputs may go beyond the power supplies without phase inversion (as shown in Figure 1) unlike some other op amps.

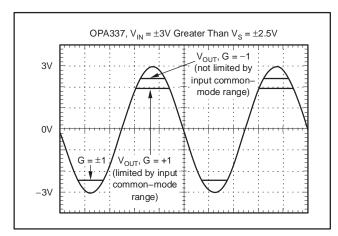


Figure 1. OPA337—No Phase Inversion with Inputs Greater than the Power-Supply Voltage

Normally, input currents are 0.2pA. However, large inputs (greater than 500mV beyond the supply rails) can cause excessive current to flow in or out of the input pins. Therefore, as well as keeping the input voltage below the maximum rating, it is also important to limit the input current to less than 10mA. This is easily accomplished with an input resistor as shown in Figure 2.

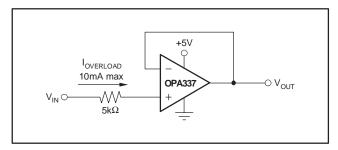


Figure 2. Input Current Protection for Voltages
Exceeding the Supply Voltage

#### **USING THE OPA338 IN LOW GAINS**

The OPA338 series is optimized for gains greater than or equal to 5. It has significantly wider bandwidth (12.5MHz) and faster slew rate (4.6V/ $\mu$ s) when compared to the OPA337 series. The OPA338 series can be used in lower gain configurations at low frequencies while maintaining its high slew rate with the proper compensation.

Figure 3 shows the OPA338 in a unity-gain buffer configuration. At dc, the compensation capacitor  $C_1$  is effectively *open* resulting in 100% feedback (closed-loop gain = 1). As frequency increases,  $C_1$  becomes lower impedance and closed-loop gain increases, eventually becoming  $1 + R_2/R_1$  (in this case 5, which is equal to the minimum gain required for stability).

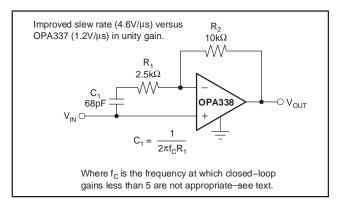


Figure 3. Compensation of the OPA338 for Unity-Gain Buffer



The required compensation capacitor value can be determined from the following equation:

$$C_1 = 1/(2\pi f_C R_1)$$

Since  $f_C$  may shift with process variations, it is recommended that a value less than  $f_C$  be used for determining  $C_1$ . With  $f_C=1$ MHz and  $R_1=2.5k\Omega$ , the compensation capacitor is about 68pF.

The selection of the compensation capacitor  $C_1$  is important. A proper value ensures that the closed-loop circuit gain is greater than or equal to 5 at high frequencies. Referring to the *Open-Loop Gain vs Frequency* plot in the Typical Characteristics section, the OPA338 gain line (dashed in the curve) has a constant slope (–20dB/decade) up to approximately 3MHz. This frequency is referred to as  $f_C$ . Beyond  $f_C$  the slope of the curve increases, suggesting that closed-loop gains less than 5 are not appropriate.

Figure 4 shows a compensation technique using an inverting configuration. The low-frequency gain is set by the resistor ratio while the high-frequency gain is set by the capacitor ratio. As with the noninverting circuit, for frequencies above  $f_C$  the gain must be greater than the recommended minimum stable gain for the op amp.

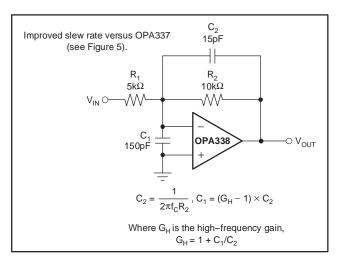


Figure 4. Inverting Compensation Circuit of the OPA338 for Low Gain

Resistors  $R_1$  and  $R_2$  are chosen to set the desired dc signal gain. Then the value for  $C_2$  is determined as follows:

$$C_2 = 1/(2\pi f_C R_2)$$

C<sub>1</sub> is determined from the desired high-frequency gain (G<sub>H</sub>):

$$C_1 = (G_H - 1) \times C_2$$

For a desired dc gain of 2 and high-frequency gain of 10, the following resistor and capacitor values result:

$$R_1 = 10k\Omega$$
  $C_1 = 150pF$   $R_2 = 5k\Omega$   $C_2 = 15pF$ 

The capacitor values shown are the nearest standard values. Capacitor values may need to be adjusted slightly to optimize performance. For more detailed information, consult the section on *Low Gain Compensation* in the OPA846 data sheet (SBOS250) located at www.ti.com.

Figure 5 shows the large-signal transient response using the circuit given in Figure 4. As shown, the OPA338 is stable in low gain applications and provides improved slew rate performance when compared to the OPA337.

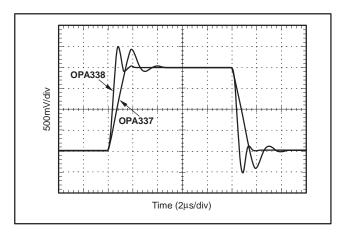


Figure 5. G = 2, Slew-Rate Comparison of the OPA338 and the OPA337

#### TYPICAL APPLICATION

See Figure 6 for the OPA2337 in a typical application. The ADS7822 is a 12-bit, micropower, sampling analog-to-digital converter available in the tiny MSOP-8 package. As with the OPA2337, it operates with a supply voltage as low as +2.7V. When used with the miniature SOT23-8 package of the OPA2337, the circuit is ideal for space-limited and low-power applications. In addition, the OPA2337's high input impedance allows large value resistors to be used which results in small physical capacitors, further reducing circuit size. For further information, consult the ADS7822 data sheet (SBAS062) located at www.ti.com.



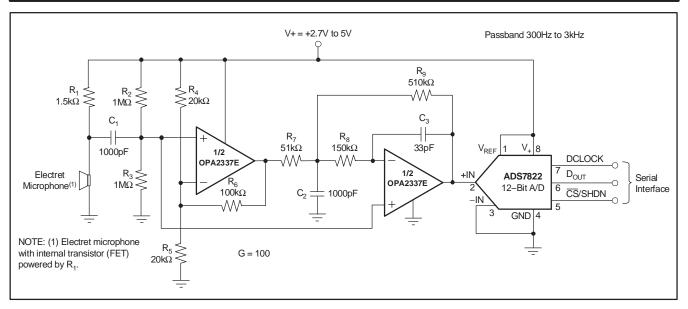


Figure 6. Low-Power, Single-Supply, Speech Bandpass Filtered Data Acquisition System

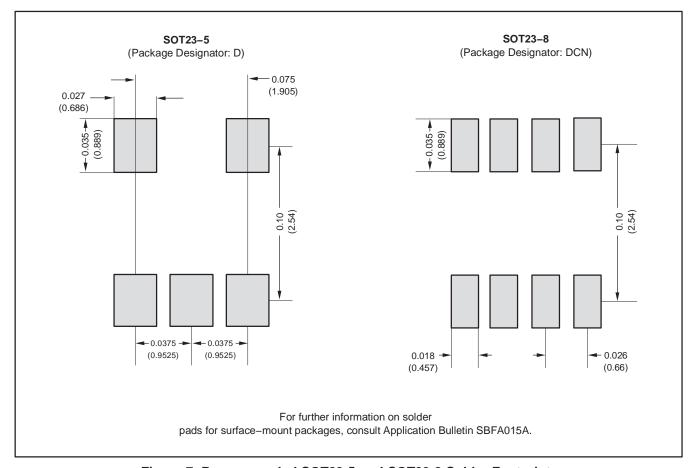


Figure 7. Recommended SOT23-5 and SOT23-8 Solder Footprints

20-Feb-2012

#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
OPA2337EA/250	ACTIVE	SOT-23	DCN	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA2337EA/250G4	ACTIVE	SOT-23	DCN	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA2337EA/3K	ACTIVE	SOT-23	DCN	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA2337EA/3KG4	ACTIVE	SOT-23	DCN	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA2337PA	ACTIVE	PDIP	Р	8	50	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	
OPA2337PAG4	ACTIVE	PDIP	Р	8	50	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	
OPA2337UA	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA2337UA/2K5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA2337UA/2K5G4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA2337UAG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA2338EA/250	ACTIVE	SOT-23	DCN	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
OPA2338EA/250G4	ACTIVE	SOT-23	DCN	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
OPA2338EA/3K	ACTIVE	SOT-23	DCN	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
OPA2338EA/3KG4	ACTIVE	SOT-23	DCN	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
OPA2338UA	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA2338UA/2K5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA2338UA/2K5G4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	



20-Feb-2012

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
OPA2338UAG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA337EA/250	ACTIVE	MSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAUAC	GLevel-2-260C-1 YEAR	
OPA337EA/250G4	ACTIVE	MSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAUAC	GLevel-2-260C-1 YEAR	
OPA337EA/2K5	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAC	GLevel-2-260C-1 YEAR	
OPA337EA/2K5G4	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAC	GLevel-2-260C-1 YEAR	
OPA337NA/250	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
OPA337NA/250G4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
OPA337NA/3K	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
OPA337NA/3KG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
OPA337PA	ACTIVE	PDIP	Р	8	50	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	
OPA337PAG4	ACTIVE	PDIP	Р	8	50	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	
OPA337UA	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA337UA/2K5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA337UA/2K5G4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA337UAG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA338NA/250	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA338NA/250G4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA338NA/3K	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	



#### PACKAGE OPTION ADDENDUM

20-Feb-2012

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
OPA338NA/3KG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA338UA	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
OPA338UAG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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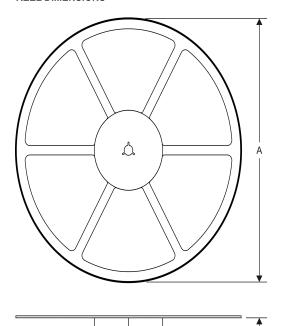
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### PACKAGE MATERIALS INFORMATION

www.ti.com 20-Apr-2012

#### TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**



#### **TAPE DIMENSIONS**



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### TAPE AND REEL INFORMATION

#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2337EA/250	SOT-23	DCN	8	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA2337EA/3K	SOT-23	DCN	8	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA2337UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA2338EA/250	SOT-23	DCN	8	250	180.0	8.4	3.2	3.1	1.39	4.0	8.0	Q3
OPA2338EA/3K	SOT-23	DCN	8	3000	180.0	8.4	3.2	3.1	1.39	4.0	8.0	Q3
OPA2338UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA337EA/250	MSOP	DGK	8	250	180.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA337EA/2K5	MSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA337NA/250	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA337NA/3K	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA337NA/3K	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA337UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

www.ti.com 20-Apr-2012



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2337EA/250	SOT-23	DCN	8	250	195.0	200.0	45.0
OPA2337EA/3K	SOT-23	DCN	8	3000	195.0	200.0	45.0
OPA2337UA/2K5	SOIC	D	8	2500	346.0	346.0	29.0
OPA2338EA/250	SOT-23	DCN	8	250	210.0	185.0	35.0
OPA2338EA/3K	SOT-23	DCN	8	3000	210.0	185.0	35.0
OPA2338UA/2K5	SOIC	D	8	2500	346.0	346.0	29.0
OPA337EA/250	MSOP	DGK	8	250	210.0	185.0	35.0
OPA337EA/2K5	MSOP	DGK	8	2500	346.0	346.0	29.0
OPA337NA/250	SOT-23	DBV	5	250	180.0	180.0	18.0
OPA337NA/3K	SOT-23	DBV	5	3000	180.0	180.0	18.0
OPA337NA/3K	SOT-23	DBV	5	3000	203.0	203.0	35.0
OPA337UA/2K5	SOIC	D	8	2500	346.0	346.0	29.0

# P (R-PDIP-T8)

#### PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



# DBV (R-PDSO-G5)

### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-178 Variation AA.



# DBV (R-PDSO-G5)

### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



# DGK (S-PDSO-G8)

# PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DCN (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)

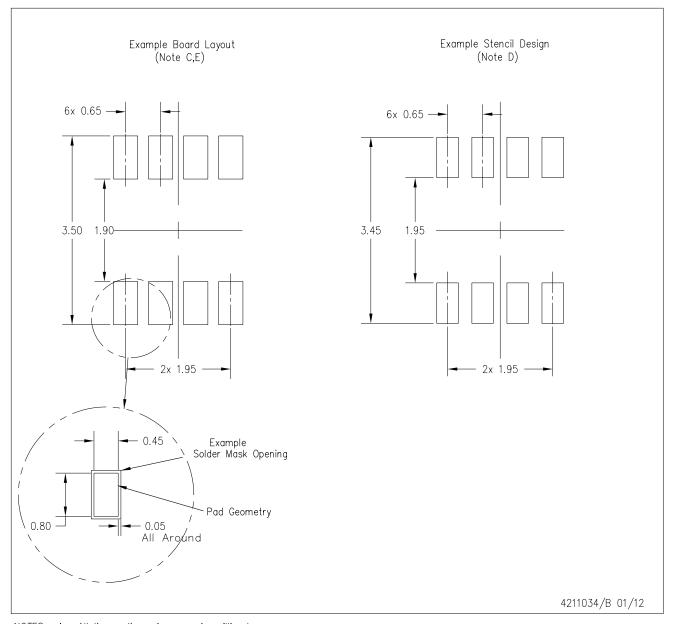


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Package outline exclusive of metal burr & dambar protrusion/intrusion.
- D. Package outline inclusive of solder plating.
- E. A visual index feature must be located within the Pin 1 index area.
- F. Falls within JEDEC MO-178 Variation BA.
- G. Body dimensions do not include flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.



DCN (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## D (R-PDSO-G8)

#### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



# D (R-PDSO-G8)

### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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